# P4KE530 & P4KE550

Vishay General Semiconductor

# **TRANSZORB<sup>®</sup> Transient Voltage Suppressors**



- · Glass passivated chip junction
- Available in uni-directional only
- Excellent clamping capability
- Very fast response time
- Low incremental surge resistance
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

## **TYPICAL APPLICATIONS**

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting on ICs, MOSFET, signal lines of sensor units for consumer, computer, industrial and telecommunication.

## **MECHANICAL DATA**

Case: DO-204AL, molded epoxy over passivated chip Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS compliant, commercial grade Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix meets JESD 201 class 1A whisker test Polarity: Color band denotes cathode end

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	P4KE530	P4KE550	UNIT		
Power dissipation on infinite heatsink at $T_L = 75 \text{ °C}$ (Fig. 4)	PD	1.0		W		
Peak pulse power dissipation $^{(1)(2)}$ (Fig. 1)	P <sub>PPM</sub>	300		W		
Stand-off voltage	V <sub>WM</sub>	477	495	V		
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 55 to + 150		°C		

#### Notes:

(1) Non repetitive current pulse per Fig. 3 and derated above 25 °C per Fig. 2

(2) Peak pulse power waveform is 10/1000 µs

**PRIMARY CHARACTERISTICS** 

V<sub>BR</sub> uni-directional

P<sub>PPM</sub>

 $\mathsf{P}_\mathsf{D}$ 

V<sub>WM</sub>

 $V_{C}$ 

T<sub>.1</sub> max.

DO-204AL (DO-41)

530 V, 550 V

300 W

1.0 W 477 V, 495 V

760 V

150 °C

### Document Number: 88366 Revision: 20-Oct-08



RoHS

COMPLIANT



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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25$ °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS	SYMBOL	P4KE530	P4KE550	UNIT	
Minimum breakdown voltage	100 μA	V <sub>BR</sub>	530	550	V	
Max. clamping voltage	400 mA, 10/1000 µs waveform	V <sub>C</sub>	760		V	
Maximum DC reverse leakage current	at V <sub>WM</sub>	I <sub>D</sub>	1.0		μA	
Typical temperature coefficient	of V <sub>BR</sub>		650		mV/°C	
Typical capacitance	1 MHz, V <sub>R</sub> = 0 V	CJ	90		pF	
	1 MHz, V <sub>R</sub> = 200 V	CJ	7.5		pF	

<b>THERMAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	P4KE530	P4KE550	UNIT		
Typical thermal resistance, junction to lead	$R_{ ext{ heta}JL}$	75		°C/W		
Typical thermal resistance, junction to ambient	$R_{ ext{ heta}JA}$	125		°C/W		

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
P4KE530-E3/54	0.350	54	5500	13" diameter paper tape and reel	
P4KE550-E3/54	0.350	54	5500	13" diameter paper tape and reel	

## **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

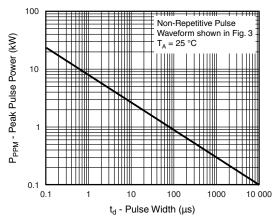


Figure 1. Peak Pulse Power Rating Curve

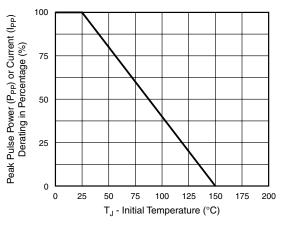
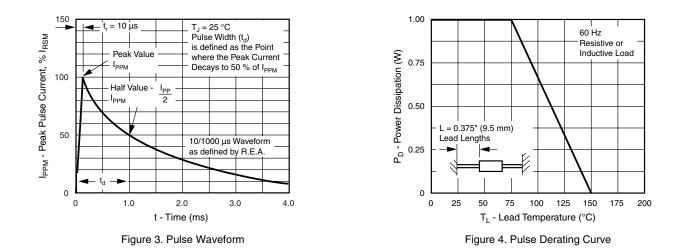


Figure 2. Pulse Power or Current vs. Initial Junction Temperature

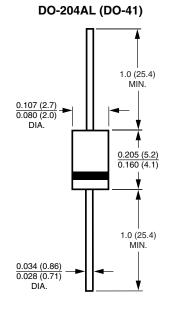


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## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



## **APPLICATION NOTES**

- Respect Thermal Resistance (PCB Layout) as the temperature coefficient also contributes to the clamping voltage
- Select minimum breakdown voltage, so you get acceptable power dissipation and PCB tie point temperature. Devices with higher breakdown voltage will have a shorter conduction time and will dissipate less power
- Clamping voltage is influenced by internal resistance - design approximation is 7 V per 100 mA slope

- Keep temperature of TVS lower than TOPSwitch<sup>®</sup> as a recommendation
- Maximum current is determined by the maximum T<sub>J</sub> and can be higher than 300 mA. Contact supplier for different clamping voltage/current arrangements
- Minimum breakdown voltage can be customized for other applications. Contact supplier
- TOPSwitch is a registered trademark of Power Integrations, Inc.



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